

IN THE CLAIMS:

Please amend and re-number claims 9-20, cancel claims 20-25, and add claims 26 - 49 as follows.

1 1. (Original): A liquid crystal display device comprising:
2 a pair of substrates,
3 a liquid crystal layer interposed between said pair of substrates,
4 a wiring having a stacked structure layer formed on one of said pair of
5 substrates,
6 a transparent conductive film formed over said wiring,
7 said wiring includes a first layer of aluminum or an alloy comprising
8 essentially of aluminum, and at least a second layer of material selected from the group
9 including of molybdenum, aluminum, chromium, tungsten, silver, and copper.

1 2. (Original): The liquid crystal display device according to claim 1
2 wherein said second layer is formed on said first layer.

1 3. (Original): The liquid crystal display device according to claim 1
2 wherein said transparent conductive film includes at least one of: ITO, IZO and IGO.

1 4. (Original): The liquid crystal display device according to claim 1
2 further including a plurality of pixel parts being constructed with a plurality of gate lines
3 and a plurality of drain lines arranged in a matrix on one of said pair of substrates, and a
4 switching element being provided in each of said pixel parts,
5 wherein one of said plurality of drain lines comprises said wiring.

1 5. (Original): The liquid crystal display device according to claim 1
2 further including a plurality of pixel parts being constructed with a plurality of gate lines
3 and a plurality of drain lines arranged in a matrix on one of said pair of substrates, and a
4 switching element being provided in each of said pixel parts,
5 wherein one of said plurality of gate lines comprises said wiring .

1 6. (Original): The liquid crystal display device according to claim 5
2 wherein said plurality of gate lines are formed along a first direction in one of said pair of
3 substrates, said plurality of drain lines formed along a second direction in one of said pair
4 of substrates, a plurality of counter voltage signal lines formed along the first direction in
5 one of said pair of substrates,
6 wherein said one of plurality of counter voltage signal lines comprises said
7 wiring.

1 7. (Original): The liquid crystal display device according to claim 6
2 further including a counter electrode disposed in said pixel part and connected with said
3 one of plurality of counter voltage signal lines, said counter electrode having a rectilinear
4 shape or a comb shape.

1 98. (Re-numbered): The liquid crystal display device according to
2 claim 7 further including a comb-shape pixel electrode disposed in said pixel part and
3 connected with said switching element.

1 109. (Re-numbered and Currently amended): The liquid crystal display
2 device according to claim 9-8 further including an insulation layer, wherein said counter
3 electrode is formed on one of said pair of ~~electrodes~~substrates, said insulating layer is
4 formed over said counter electrode, said pixel electrode is formed on said insulating
5 layer.

1 4410. (Re-numbered): The liquid crystal display device according to
2 claim 9-8 further including a scan signal applied through one of said plurality of gate
3 lines to said switching element, a video signal is applied through one of said plurality of
4 drain lines and said switching element to said pixel electrode, said switching element
5 formed proximate to a crossing point between said one of said of drain lines and said one
6 of said gate lines.

1 4211. (Re-numbered): The liquid crystal display device according to
2 claim 9-8 wherein said pixel electrode has a zigzag-shaped structure.

1 4312. (Re-numbered): The liquid crystal display device according to
2 claim 9-8 wherein said pixel electrode has a comb-shaped structure.

1 4413. (Re-numbered and Currently amended): The liquid crystal display
2 device according to claim 43-12 further including an insulation layer and an organic
3 layer, wherein said counter electrode is formed on one of said pair of
4 ~~electrodes~~_{substrates}, said insulating layer is formed over said counter electrode, said
5 organic layer is formed over said insulating layer, said pixel electrode is formed on said
6 organic layer.

1 4514. (Re-numbered): A liquid crystal display device comprising:
2 a pair of substrates,
3 a liquid crystal layer interposed between said pair of substrates,
4 drain lines and gate lines formed on one of said pair of substrates and
5 crossing each other in a matrix form,
6 counter voltage lines formed on one of said pair of substrates and being
7 disposed between said gate lines,
8 wherein at least one of said drain lines, said gate lines and said counter
9 voltage lines includes a multi-layered structure covered with a transparent conductive
10 film, said multi-layered structure comprising an aluminum layer or an alloy layer

11 comprising essentially of aluminum and a high-melting point metal layer, said transparent
12 conductive film including one of ITO, IZO and IGO.

1 +615. (Re-numbered): The liquid crystal display device according to
2 claim +5-14 further including a pixel electrode formed on one of said pair of substrates
3 and having a comb-shaped structure, and a switching element formed proximate to a
4 crossing point between said at least one of said drain lines and said gate lines and
5 connected with said pixel electrode.

1 +716. (Re-numbered): The liquid crystal display device according to
2 claim +6-15 further including a sheet of counter electrode disposed on one of said pair of
3 substrates in opposed relation to said pixel electrode and connected with one of said
4 counter voltage lines.

1 +817. (Re-numbered): The liquid crystal display device according to
2 claim +6-15 further including a comb-shaped counter electrode disposed on one of said
3 pair of substrates in opposed relation to said pixel electrode and connected with one of
4 said counter voltage lines.

1 +918. (Re-numbered and Currently amended): A liquid crystal display
2 device comprising:
3 a pair of substrates,
4 a liquid crystal layer interposed therebetween,
5 a thin film transistor having a gate electrode, a source electrode and a
6 drain electrode formed on one of said pair of substrates;
7 a gate line connected to said gate electrode,
8 a drain line connected to said drain electrode,
9 a pixel electrode connected to said source electrode and having an
10 approximately a slit shape structure, a comb-shaped structure, or a zigzag-shaped
11 structure,

12 a counter electrode being any of ITO, IZO or IGO and arranged in
13 opposed relation to said pixel electrode,
14 a counter voltage line connected to said counter electrode,
15 wherein said counter voltage line comprising a triple-layered structure
16 including an alumina first layer, a high-melting point metal second layer, and a third layer
17 of aluminum or an alloy comprising essentially aluminum,
18 said high-melting point metal second layer connected to said counter
19 electrode through an opening in said alumina first layer.

1 2019. (Re-numbered): The liquid crystal display device according to
2 claim 19-18 wherein said alumina first layer and said high-melting point metal second
3 layer are formed on said third layer, and

4 said high-melting point metal second layer formed through said alumina
5 layer from a surface side of a portion of said alumina layer to said third layer, and
6 connected to said counter electrode.

20 - 25. (Canceled)

1 26. (New): A liquid crystal display device comprising:
2 a pair of substrates;
3 a liquid crystal layer interposed between said pair of substrates;
4 drain lines and gate lines formed on one of said pair of substrates and
5 crossing each other in a matrix form, each crossing of said drain lines and gate lines
6 defining a pixel;
7 a switching element associated with and disposed relative to each pixel;
8 a sheet-like counter electrode comprising a transparent conductive film
9 arranged at each pixel;
10 a counter voltage line formed on said counter electrode, said counter
11 voltage line including a multi-layered structure comprising a first molybdenum layer, an
12 aluminum layer, and a second molybdenum layer in this order;

13 a first insulating layer formed on said counter electrode and said counter
14 voltage line;
15 a second insulating layer formed on said first insulating layer; and
16 a pixel electrode comprising a transparent conductive film which is
17 electrically connected to said switching element.

1 27. (New): The liquid crystal display device according to claim 26,
2 wherein said aluminum layer includes an alloy layer comprising essentially of aluminum.

1 28. (New): The liquid crystal display device according to claim 26,
2 wherein at least one of said first molybdenum layer and said second molybdenum layer
3 includes an alloy layer comprising essentially of molybdenum.

1 29. (New): The liquid crystal display device according to claim 26,
2 wherein said pixel electrode has an approximately linear-shaped structure, zigzag-shaped
3 structure, slit shape structure, or comb-shaped structure.

1 30. (New): The liquid crystal display device according to claim 29,
2 wherein said pixel electrode extends in the same direction as said gate electrode.

1 31. (New): The liquid crystal display device according to claim 26,
2 wherein said transparent conductive film of said pixel electrode and of said counter
3 electrode each includes one of ITO, IZO and IGO.

1 32. (New): The liquid crystal display device according to claim 31,
2 wherein said transparent conductive film is a polycrystalline.

1 33. (New): The liquid crystal display device according to claim 31,
2 wherein said transparent conductive film is amorphous.

1 34. (New): The liquid crystal display device according to claim 31,
2 wherein said transparent conductive film of said counter electrode and of said counter
3 electrode are of different materials.

1 35. (New): The liquid crystal display device according to claim 34,
2 wherein said transparent conductive film is a polycrystalline.

1 36. (New): The liquid crystal display device according to claim 34,
2 wherein said transparent conductive film is amorphous.

1 37. (New): The liquid crystal display device according to claim 26,
2 wherein said switching element is a thin film transistor and said first insulating layer is a
3 gate insulating layer of said thin film transistor.

1 38. (New): A liquid crystal display device comprising:
2 a pair of substrates;
3 a liquid crystal layer interposed between said pair of substrates;
4 a sheet-like first electrode comprising a transparent conductive film
5 arranged on one of said pair of substrates;
6 a multi-layered structure line comprising a first molybdenum layer and an
7 aluminum layer and a second molybdenum layer in this order formed on said first
8 electrode;
9 a first insulating layer formed on said first electrode and said multilayered
10 structure line;
11 second insulating layer formed on said first insulating layer; and
12 second electrode comprising a transparent conductive film formed on said
13 second insulating layer.

1 39. (New): The liquid crystal display device according to claim 38,
2 wherein said aluminum layer includes an alloy layer comprising essentially of aluminum.

1 40. (New): The liquid crystal display device according to claim 38,
2 wherein at least one of said first molybdenum layer and said second molybdenum layer of
3 multi-layered structure line includes an alloy layer comprising essentially of
4 molybdenum.

1 41. (New): The liquid crystal display device according to claim 38,
2 wherein said second electrode has an approximately linear-shaped structure,
3 zigzag-shaped structure, slit shape structure, or comb-shaped structure.

1 42. (New): The liquid crystal display device according to claim 38,
2 further comprising drain lines and gate lines formed on one of said pair of substrates anal
3 crossing each other in a matrix form, pixels being formed corresponding to domains
4 surrounded by crossings of said drain lines and said gate lines, wherein said first
5 electrode and said second are arranged for each pixel.

1 43. (New): The liquid crystal display device according to claim 42,
2 wherein said transparent conductive film is a polycrystalline.

1 44. (New): The liquid crystal display device according to claim 42,
2 wherein said transparent conductive film is an amorphous.

1 45. (New): The liquid crystal display device according to claim 38,
2 wherein said transparent conductive film of said first electrode and of said second
3 electrode each includes one of ITO, IZO and IGO.

1 46. (New): The liquid crystal display device according to claim 45,
2 wherein transparent conductive film of said first electrode and said second electrode are
3 different material.

1 47. (New): The liquid crystal display device according to claim 45,
2 wherein said transparent conductive film is a polycrystalline.

1 48. (New): The liquid crystal display device according to claim 45,
2 wherein said transparent conductive film is an amorphous.

1 49. (New): The liquid crystal display device according to claim 42,
2 further comprising a switching element arranged for each pixel, wherein said switching
3 element is connected said second electrode.

1 50. (New): The liquid crystal display device according to claim 49,
2 wherein said switching element is a thin film transistor and said first insulating layer is a
3 gate insulating layer of said thin film transistor.

1 51. (New): The liquid crystal display device according to claim 42,
2 wherein said multi-layered structure line is arranged over two or more pixels.

1 52. (New): The liquid crystal display device according to claim 51,
2 wherein said multi-layered structure line extends in the same direction as said gate
3 electrode.

1 53. (New): The liquid crystal display device according to claim 41,
2 wherein said second electrode in the as same direction as said gate electrode.